

SOT-23 BIPOLAR TRANSISTORS TRANSISTOR(NPN)

FEATURES

- * Epitaxial planar die construction
- * Complementary PNP Type available(MMBT2907A)

MECHANICAL DATA

- * Case: Molded plastic
- * Epoxy: UL 94V-O rate flame retardant
- * Lead: MIL-STD-202E method 208C guaranteed
- * Mounting position: Any * Weight: 0.008 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 $^{\circ}\text{C}$ ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

SOT-23 COLLECTOR 0.055(1.40) 0.047(1.20) EMITTER 3 0.118(3.00) 0.110(2.80) Dimensions in inches and (millimeters)

MAXIMUM RATINGES (@ TA = 25° C unless otherwise noted)

RATINGS	SYMBOL	VALUE	UNITS	
Max. Steady State Power Dissipation ⁽¹⁾ @T _A =25°C Derate above 25°C	Pb	300	mW	
Max. Operating Temperature Range	TJ	150	°C	
Storage Temperature Range	Тѕтс	-55 to +150	°C	

ELECTRICAL CHARACTERISTICS (@ TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS
Thermal Resistance Junction to Ambient	R _{θJA}	-	-	417	°C/W

Notes: 1. Alumina=0.4*0.3*0.024in. 99.5% alumina. 2. " Fully ROHS Compliant ", "100% Sn plating (Pb-free)".

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ELECTRICAL CHARACTERISTICS (@TA=25°C unless otherwise noted)

	Chatacteristic	Symbol	Min	Max	Linit
		Syllibol	Min	IVIAX	Unit
OFF CHARA	CTERISTICS	_			1
Collector-Emi	tter Breakdown Voltage (I _C = 10mAdc, I _B = 0)	V _(BR) CEO	40	-	Vdc
Collector-Bas	e Breakdown Voltage (I _C = 10mAdc, I _E = 0)	V _(BR) CBO	75	-	Vdc
Emitter-Base	Breakdown Voltage (I _E = 10mAdc, I _C = 0)	V _{(BR)EBO}	6.0	-	Vdc
Collector Cuto	off Current (V _{CE} = 60Vdc,V _{EB(off)} = 3.0Vdc	ICEX	-	0.1	uAdc
Collector Cuto	off Current (V_{CB} = 60 V_{dc} , I_{E} = 0)	I _{CBO}	-	0.01	uAdc
	$(V_{CB}=60Vdc, I_{E}=0, TA=125^{\circ}C)$.CBO	-	10	uAdc
Emitter Cutoff	f Current (V _{EB} = 3.0Vdc, I _C = 0)	I _{EBO}	-	0.1	uAdc
Base Cutoff C	Current (V _{CE} = 60Vdc, V _{EB(off)} = 3.0Vdc	I _{BL}	-	20	nAdc
ON CHARAC	TERISTICS				
DC Current G	ain (I _C = 10mAdc, V _{CE} = 10Vdc, TA= -55°C)	1.55	35	-	-
	(I_C = 500mAdc, V_{CE} = 10Vdc) (1)	hFE	40	-	
Collector-Emi	tter Saturation Voltage (1) (I _C = 150mAdc, I _B = 15mAdc)	.,	-	0.3	Vdc
	$(I_C = 500 \text{mAdc}, I_B = 50 \text{mAdc})$	V _{CE(sat)}	-	1.0	
Base-Emitter	Saturation Voltage (1) (I _C = 150mAdc, I _B = 15mAdc)	.,	0.6	1.2	
	$(I_C = 500 \text{mAdc}, I_B = 50 \text{mAdc})$	V _{BE(sat)}	-	2.0	Vdc
SMALL-SIGN	IAL CHARACTERISTICS				
Current-Gain-	Bandwidth Product (2) (I _C = 20mAdc, V _{CE} = 20Vdc, f= 100MHz)	f _T	300	-	MHz
Input Capacit	ance (V _{EB} =0.5Vdc, I _C = 0, f= 1.0MHz)	C _{ibo}	-	25	pF
Input Impeda	nce (I _C = 1.0mAdc, V _{CE} =10Vdc, f=1.0kHz)		2.0	8.0	kW
	$(I_C = 10 \text{mAdc}, V_{CE} = 10 \text{Vdc}, f = 1.0 \text{kHz})$	h _{ie}	0.25	1.25	
Voltage Feed	back Ratio (I _C = 1.0mAdc, V _{CE} = 10Vdc, f= 1.0kHz)		-	8.0	V 40-4
	(I_C = 10mAdc, V_{CE} =10Vdc, f= 1.0kHz)	h _{re}	-	4.0	X 10 ⁻⁴
Small-Signal	Current Gain (I _C = 1.0mAdc, V _{CE} = 10Vdc, f= 1.0kHz)		50	300	
	$(I_C = 10 \text{mAdc}, V_{CE} = 10 \text{Vdc}, f = 1.0 \text{kHz})$	hfe	75	375	-
Output Admitt	tance (I _C = 1.0mAdc, V _{CE} = 10Vdc, f= 1.0kHz)		5.0	35	umhos
	$(I_C = 10 \text{mAdc}, V_{CE} = 10 \text{Vdc}, f = 1.0 \text{kHz})$	h _{oe}	25	200	
Collector Base Time Constant (I _E = 20mAdc, V _{CB} = 20Vdc, f= 31.8MHz)		rb,Cc	-	150	ps
Noise Figure	(I _C = 100mAdc, V _{CE} = 10Vdc, R _S = 1.0kW, f= 1.0kHz)	NF	-	4.0	dB
SWITCHING	CHARACTERISTICS	•	•	•	
Delay Time	(Vac= 30Vdc Vac: ro= -0.5Vdc la= 150mAdc la:= 15mAdc)	t _d	-	10	-
Rise Time	(V _{CC} = 30Vdc, V _{BE(off)} = -0.5Vdc, I _C = 150mAdc, I _{B1} = 15mAdc)	t _r	-	25	ns
Storage Time		t _s	-	225	
Fall Time	(V _{CC} = 30Vdc, I _C = 150mAdc, I _{B1} = I _{B2} = 15mAdc)		-	60	ns
	se Test: Pulse Width<300ms Duty Ovele<2.0%		<u> </u>	<u> </u>	

NOTES: 1. Pulse Test: Pulse Width≤300ms,Duty Cycle≤2.0%
2. f_T is defined as the frequency at which |hfe| extrapolates to unity



RATING AND CHARACTERISTICS CURVES (MMBT2222A)

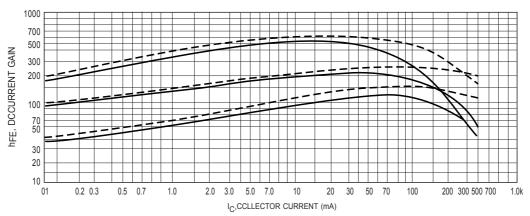


Figure 1. DC Current Gain

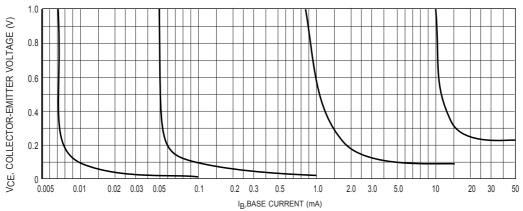


Figure 2. Collector Saturation Region

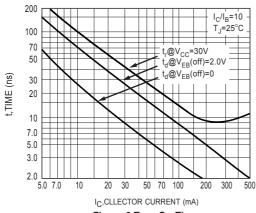


Figure 3.Turn-On Time

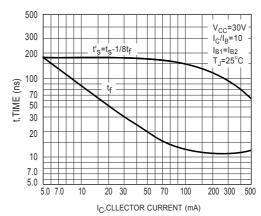
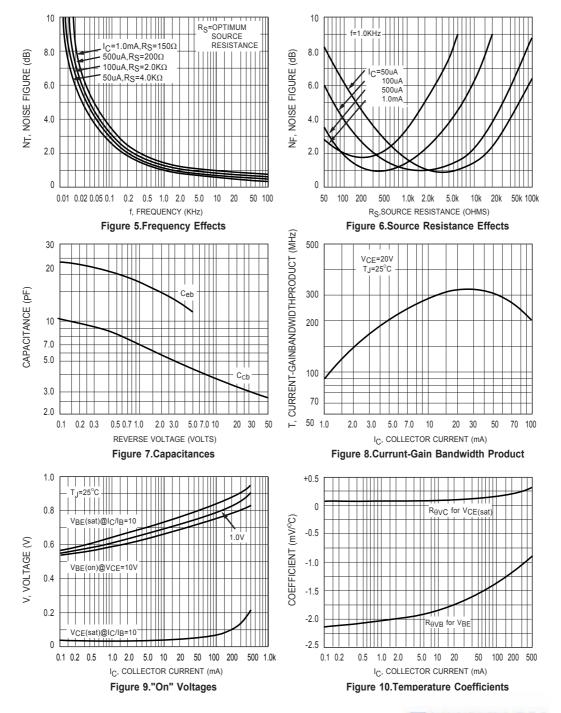


Figure 4.Turn-Off Time



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